

## N-Channel NexFET™ Power MOSFET

### FEATURES

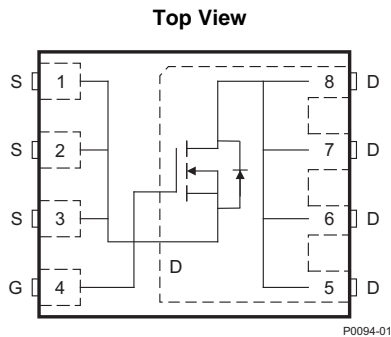
- **Ultralow  $Q_g$  and  $Q_{gd}$**
- **Low Thermal Resistance**
- **Avalanche Rated**
- **SON 5-mm × 6-mm Plastic Package**

### APPLICATIONS

- **Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems**
- **Optimized for Control FET Applications**

### DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.



### PRODUCT SUMMARY

$V_{DS}$	Drain-to-source voltage	25	V
$Q_g$	Gate charge, total (4.5 V)	6.7	nC
$Q_{gd}$	Gate charge, gate-to-drain	1.9	nC
$r_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 4.5\text{ V}$	5.4 mΩ
		$V_{GS} = 10\text{ V}$	3.6 mΩ
$V_{GS(th)}$	Threshold voltage	1.8	V

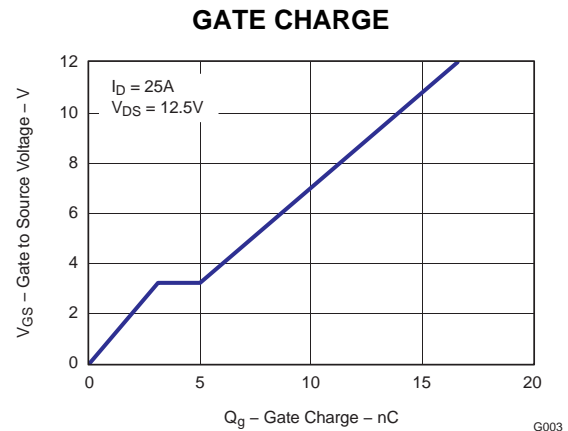
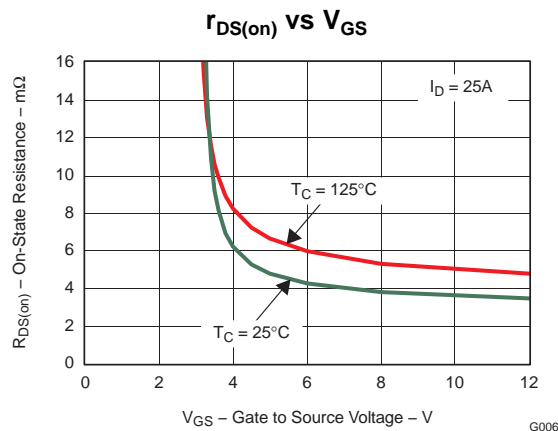
### ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD16408Q5	SON 5-mm × 6-mm plastic package	13-inch (33-cm) reel	2500	Tape and reel

### ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
$V_{DS}$	Drain-to-source voltage	25	V
$V_{GS}$	Gate-to-source voltage	–12 to 16	V
$I_D$	Continuous drain current, $T_C = 25^\circ\text{C}$	113	A
	Continuous drain current <sup>(1)</sup>	22	A
$I_{DM}$	Pulsed drain current, $T_A = 25^\circ\text{C}$ <sup>(2)</sup>	141	A
$P_D$	Power dissipation <sup>(1)</sup>	3.1	W
$T_J$ , $T_{STG}$	Operating junction and storage temperature range	–55 to 150	°C
$E_{AS}$	Avalanche energy, single-pulse $I_D = 23\text{ A}$ , $L = 0.1\text{ mH}$ , $R_G = 25\text{ }\Omega$	126	mJ

- (1) Typical  $R_{\theta JA} = 41^\circ\text{C/W}$  on 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

## ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$  unless otherwise stated

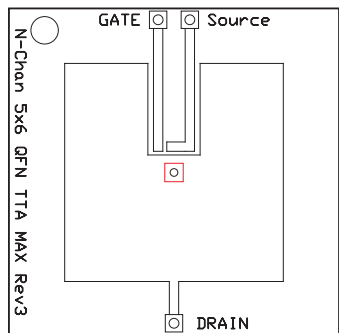
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
BV <sub>DSS</sub>	Drain-to-source voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	25			V
I <sub>DSS</sub>	Drain-to-source leakage	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 20 V	1			μA
I <sub>GSS</sub>	Gate-to-source leakage	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = −12 V to 16 V	100			nA
V <sub>GS(th)</sub>	Gate-to-source threshold voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1.4	1.8	2.1	V
r <sub>DS(on)</sub>	Drain-to-source on-resistance	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 25 A	5.4		6.8	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 25 A	3.6		4.5	mΩ
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 25 A	60			S
Dynamic Characteristics						
C <sub>ISS</sub>	Input capacitance	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 12.5 V , f = 1 MHz	990		1300	pF
C <sub>OSS</sub>	Output capacitance		760		1000	pF
C <sub>RSS</sub>	Reverse transfer capacitance		75		100	pF
R <sub>g</sub>	Series gate resistance		0.8		1.6	Ω
Q <sub>g</sub>	Gate charge total (4.5 V)	V <sub>DS</sub> = 12.5 V, I <sub>D</sub> = 25 A	6.7		8.9	nC
Q <sub>gd</sub>	Gate charge, gate-to-drain		1.9			nC
Q <sub>gs</sub>	Gate charge, gate-to-source		3.1			nC
Q <sub>g(th)</sub>	Gate charge at V <sub>th</sub>		1.8			nC
Q <sub>OSS</sub>	Output charge	V <sub>DS</sub> = 13 V, V <sub>GS</sub> = 0 V	15.7			nC
t <sub>d(on)</sub>	Turnon delay time	V <sub>DS</sub> = 12.5 V, V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A, R <sub>G</sub> = 2 Ω	11.3			ns
t <sub>r</sub>	Rise time		25			ns
t <sub>d(off)</sub>	Turnoff delay time		11			ns
t <sub>f</sub>	Fall time		10.8			ns
Diode Characteristics						
V <sub>SD</sub>	Diode forward voltage	I <sub>S</sub> = 25 A, V <sub>GS</sub> = 0 V	0.8		1	V
Q <sub>rr</sub>	Reverse recovery charge	V <sub>DD</sub> = 13 V, I <sub>F</sub> = 2 5A, di/dt = 300 A/μs	17			nC
t <sub>rr</sub>	Reverse recovery time	V <sub>DD</sub> = 13 V, I <sub>F</sub> = 25 A, di/dt = 300 A/μs	21			ns

## THERMAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$  unless otherwise stated

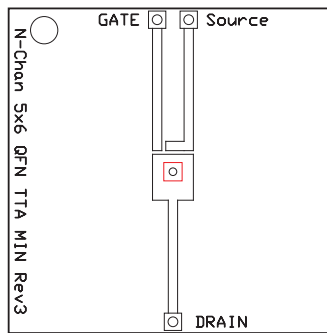
PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			1.9	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient <sup>(1) (2)</sup>			51	$^\circ\text{C}/\text{W}$

- (1)  $R_{\theta JC}$  is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB.  $R_{\theta JC}$  is specified by design, whereas  $R_{\theta JA}$  is determined by the user's board design.
- (2) Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.



M0137-01

Max  $R_{\theta JA} = 51^{\circ}\text{C/W}$   
when mounted on  
1 inch<sup>2</sup> (6.45 cm<sup>2</sup>) of  
2-oz. (0.071-mm thick)  
Cu.

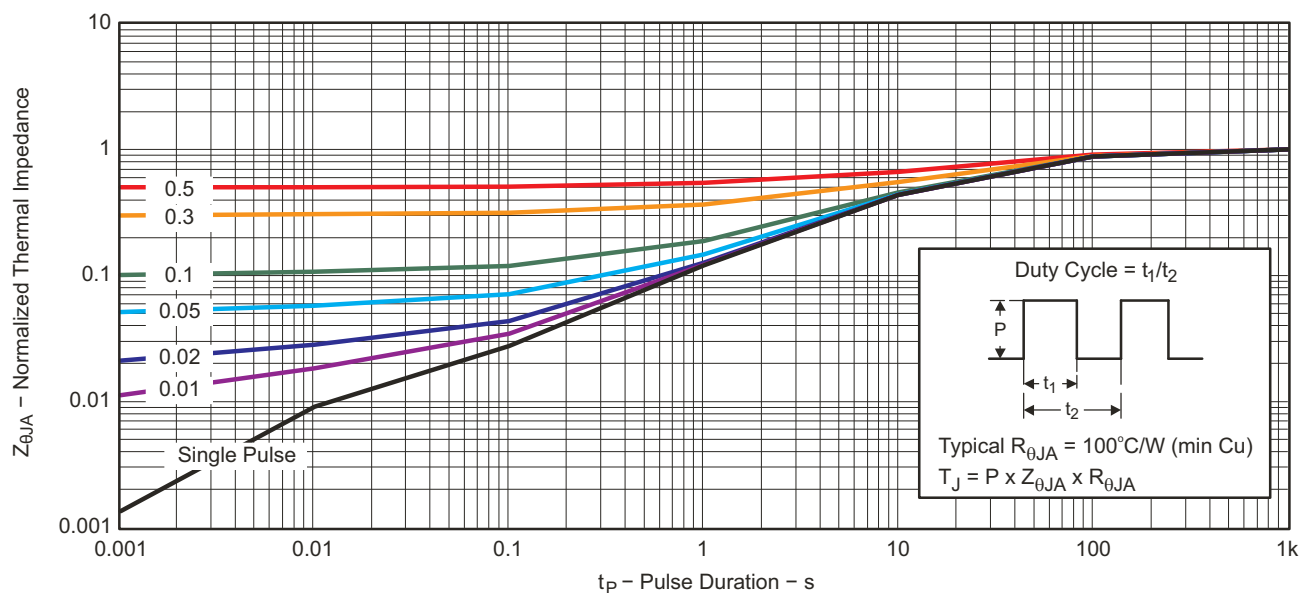


M0137-02

Max  $R_{\theta JA} = 125^{\circ}\text{C/W}$   
when mounted on  
minimum pad area of  
2-oz. (0.071-mm thick)  
Cu.

## TYPICAL MOSFET CHARACTERISTICS

$T_A = 25^{\circ}\text{C}$  unless otherwise stated



G012

Figure 1. Transient Thermal Impedance

## TYPICAL MOSFET CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$  unless otherwise stated

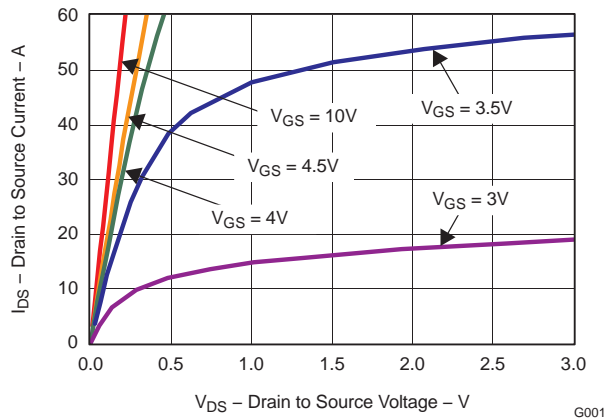


Figure 2. Saturation Characteristics

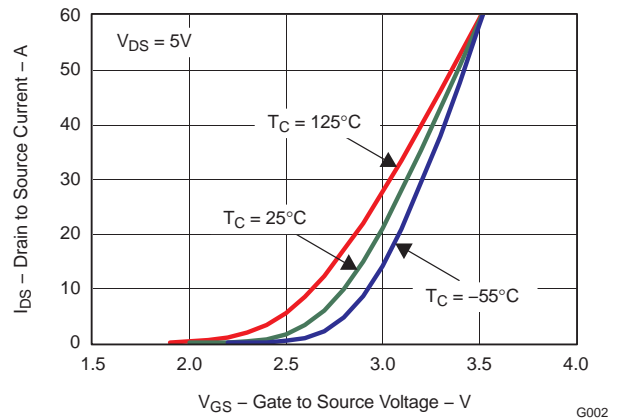


Figure 3. Transfer Characteristics

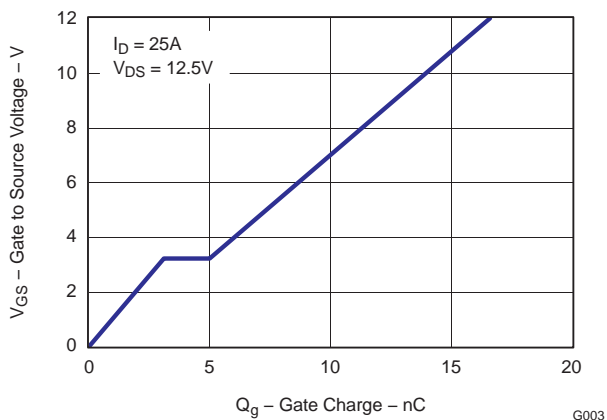


Figure 4. Gate Charge

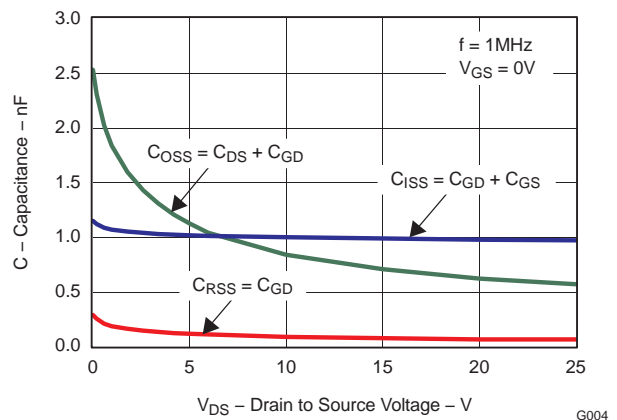


Figure 5. Capacitance

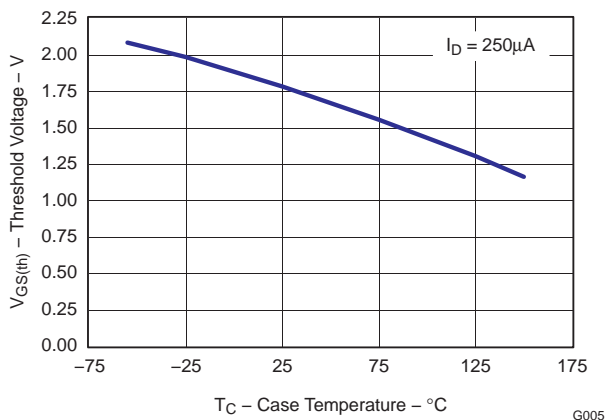


Figure 6. Threshold Voltage vs. Temperature

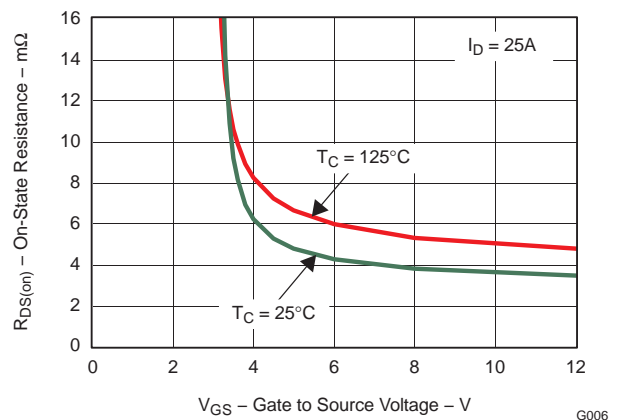
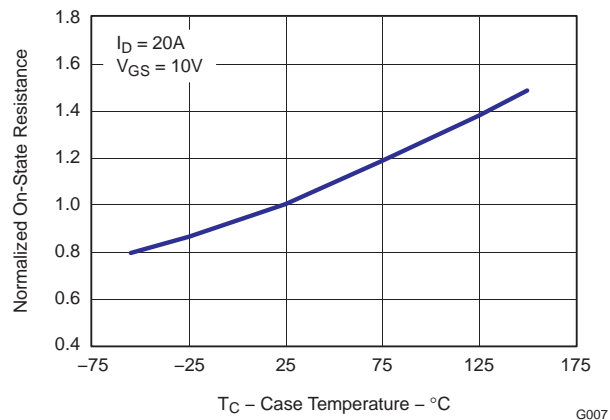


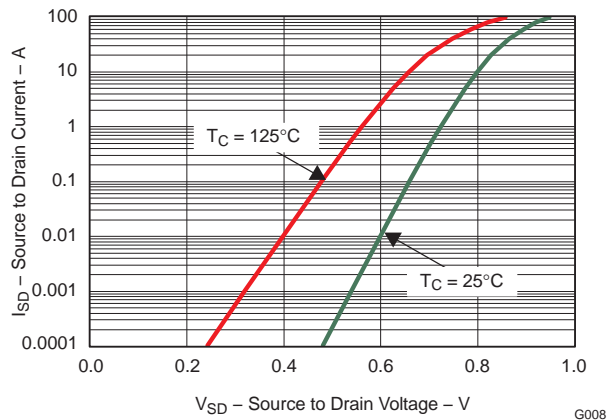
Figure 7. On-State Resistance vs. Gate-to-Source Voltage

## TYPICAL MOSFET CHARACTERISTICS (continued)

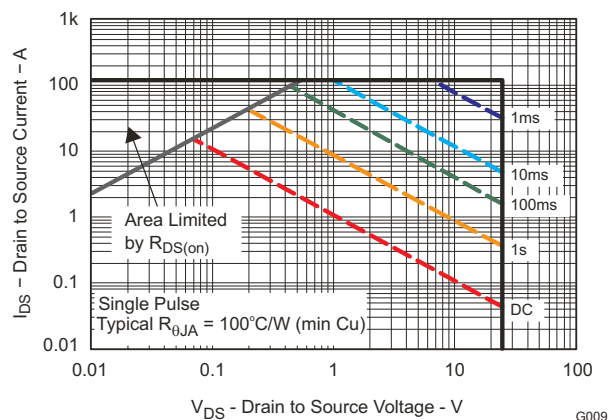
$T_A = 25^\circ\text{C}$  unless otherwise stated



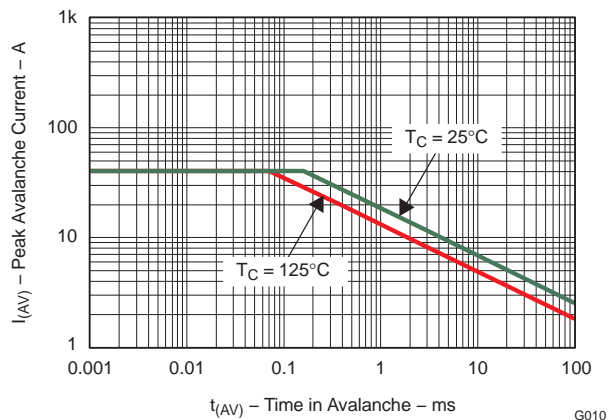
**Figure 8. Normalized On-State Resistance vs. Temperature**



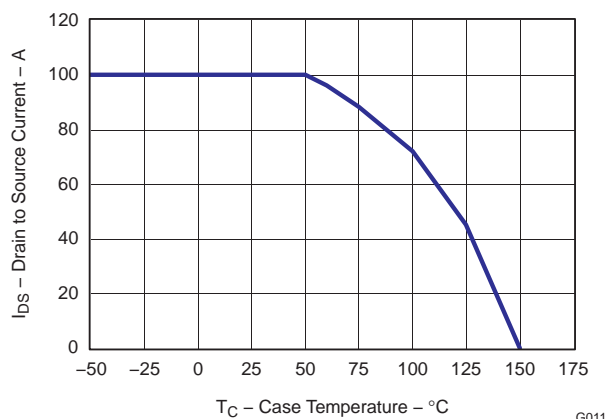
**Figure 9. Typical Diode Forward Voltage**



**Figure 10. Maximum Safe Operating Area**



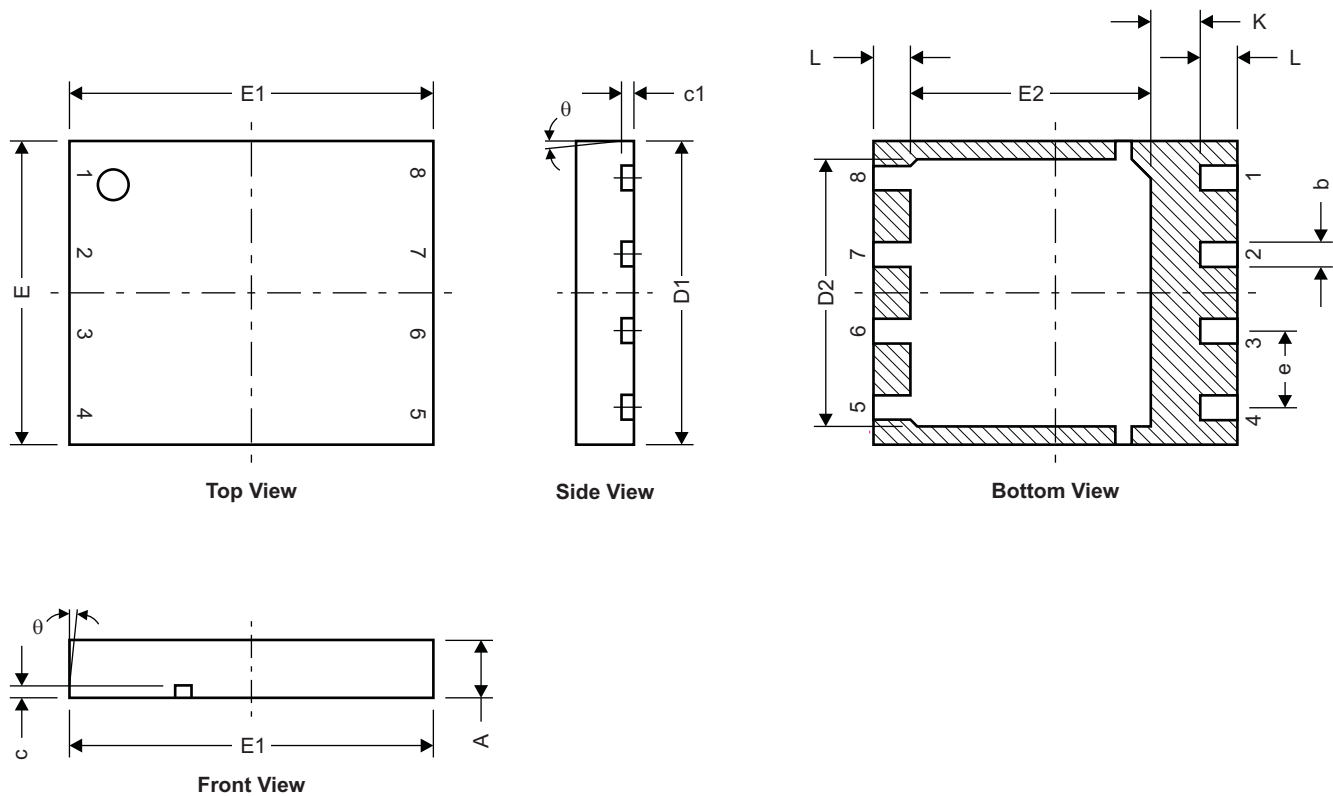
**Figure 11. Single-Pulse Unclamped Inductive Switching**



**Figure 12. Maximum Drain Current vs. Temperature**

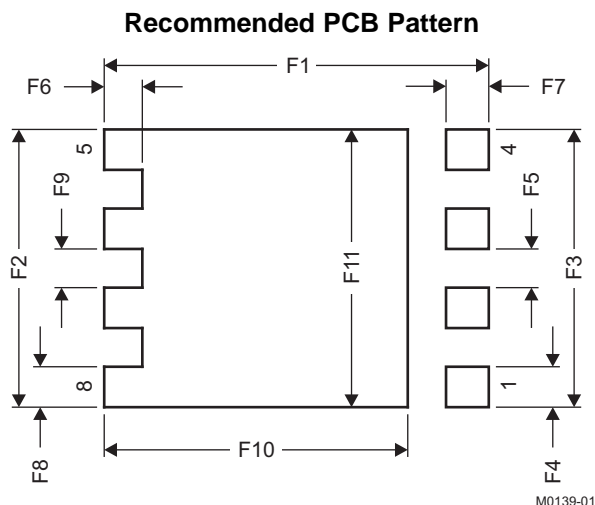
## MECHANICAL DATA

### Q5 Package Dimensions



M0140-01

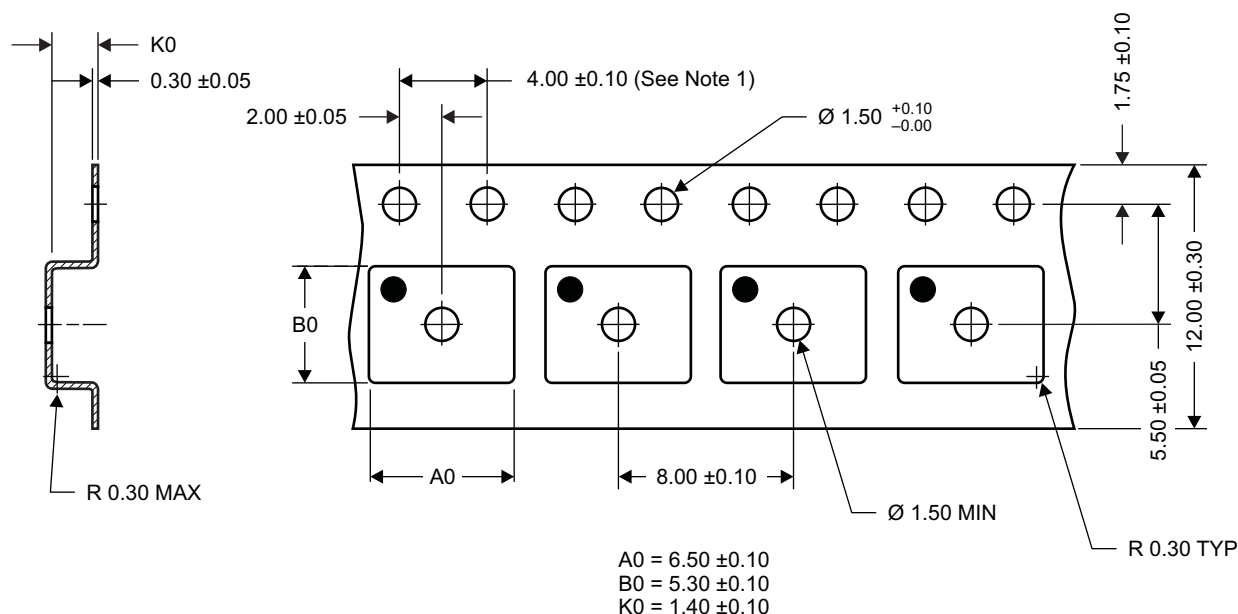
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
c	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
e	1.27 typ		0.050	
L	0.510	0.710	0.020	0.028
$\theta$	0.00	–	–	–



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note *Reducing Ringing Through PCB Layout Techniques* (SLPA005).

## Q5 Tape and Reel Information



### Notes:

1. 10-sprocket hole-pitch cumulative tolerance  $\pm 0.2$
2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
3. Material: black static-dissipative polystyrene
4. All dimensions are in mm, unless otherwise specified.
5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket
6. MSL1 260°C (IR and convection) PbF reflow compatible

## REVISION HISTORY

Changes from Revision Original (October 2009) to Revision A	Page
• Deleted environmental bullets from features list .....	<a href="#">1</a>
• Deleted package marking section from end of data sheet .....	<a href="#">7</a>



**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16408Q5	VSON-CLIP	DQH	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16408Q5	VSON-CLIP	DQH	8	2500	336.6	336.6	41.3

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### Applications

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Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
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